

Session Title: 05, TFT Technology

Session Date: August 20 (Wed.), 2025

Session Time: 09:00-10:25

Session Room: Room E (311~312)

Session Chair(s): Prof. Jun Takeya (The Univ. of Tokyo, Japan)
Prof. Hyun Suk Kim (Dongguk Univ., Korea)

## [E05-1] [Featured Invited]

09:00-09:30

Efficiency, Wavelength, and Speed Considerations for MicroLEDs in Display and Non-Display Applications

Ioannis Kymissis, Oliver Durnan, and Megan Noga (Columbia Univ., USA)

[E05-2] [Invited] 09:30-09:55

## Ferroelectric Thin Film Transistors and Their Applications

Wenwu Li (Fudan Univ., China), Fucai Liu (Univ. of Electronic Sci. and Tech. of China, China), and Junhao Chu (Fudan Univ., China)

[E05-3] 09:55-10:10

## Optimization to Obtain Grain-Boundary-Free Crystal Si Formation

Satoshi Takayama, Nobuo Sasaki (Nara Inst. of Sci. and Tech. & Sasaki Consulting, Japan), and Yukiharu Uraoka (Nara Inst. of Sci. and Tech., Japan)

[E05-4] 10:10-10:25

High-Performance a-IGZO TFT Using Solution Combustion Synthesis High-k Al<sub>2</sub>O<sub>3</sub> and HfO<sub>2</sub> Hybrid Gate Insulator

Dian Budiarti Kastian, Juan Paolo Bermundo, Candell Grace Paredes Quino, and Yukiharu Uraoka (Nara Inst. of Science and Tech., Japan)